



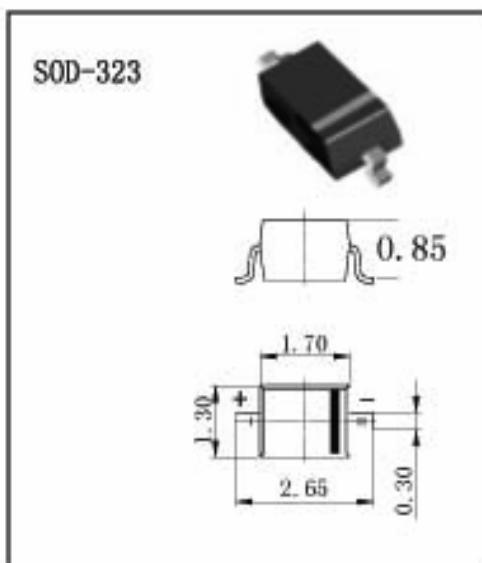
Transys
Electronics
LIMITED

RB551V-30 Schottky Diodes

FEATURES

- High current rectifier Schottky diode
- Low voltage, low inductance
- For power supply

MAKING: D



Maximum Ratings and Electrical Characteristics, Single Diode @T_A=25°C

Parameter	Symbol	Limits		Unit
Peak reverse voltage	V _{RM}	30		V
DC reverse voltage	V _R	20		V
Mean rectifying current	I _O	0.5		A
Peak forward surge current	I _{FSM}	2		A
Junction temperature	T _j	125		°C
Storage temperature	T _{stg}	-40~+125		°C

Electrical Ratings @T_A=25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _F			0.36 0.47	V	I _F =100mA I _F =500mA
Reverse current	I _R			100	μA	V _R =20V